



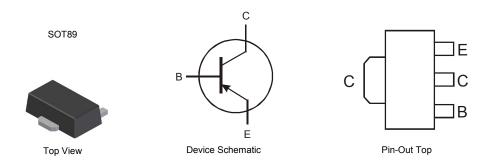
40V LOW V_{CE(sat)} PNP SURFACE MOUNT TRANSISTOR

Features

- BV_{CEO} > -40V
- I_C = -4A Continuous Collector Current
- Ultra Low Collector-Emitter Saturation Voltage
- Ideally Suited for Automated Assembly Processes
- Ideal for Medium Power Switching or Amplification Applications
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q101, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative. https://www.diodes.com/quality/product-definitions/

Mechanical Data

- Case: SOT89
- Case Material: Molded Plastic. "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plates Leads.
 Solderable per MIL-STD-202, Method 208 (§3)
- Weight: 0.055 grams (Approximate)



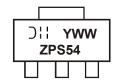
Ordering Information (Note 4)

Product	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
DSS5540X-13	ZPS54	13	12mm	2500
DSS5540XTC	ZPS54	13	12mm	4000

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/

Marking Information





Absolute Maximum Ratings @TA = 25°C unless otherwise specified

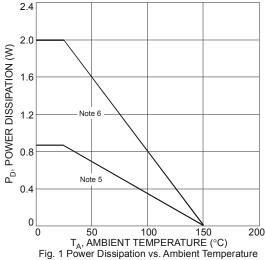
Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	-40	V
Collector-Emitter Voltage	V _{CEO}	-40	V
Emitter-Base Voltage	V _{EBO}	-6	V
Peak Pulse Collector Current	I _{CM}	-10	Α
Repetitive Peak Pulse Collector Current (Note 5)	I _{CRP}	-5	A
Continuous Collector Current	Ic	-4	Α
Peak Pulse Base Current	I _{BM}	-2	A
Continuous Base Current	I _B	-1	A

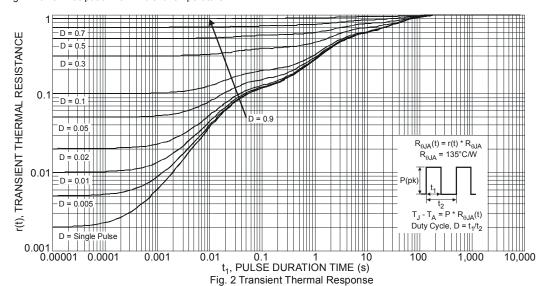
Thermal Characteristics

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 6) @ T _A = 25°C	P _D	0.9	W
Thermal Resistance, Junction to Ambient Air (Note 6) @ T _A = 25°C	$R_{\theta JA}$	139	°C/W
Power Dissipation (Note 7) @ T _A = 25°C	P _D	2	W
Thermal Resistance, Junction to Ambient Air (Note 7) @ T _A = 25°C	$R_{\theta JA}$	62.5	°C/W
Operating and Storage Temperature Range	T.I. TSTG	-55 to +150	°C

Notes:

- 5. Pulse width ≤ 10ms; Duty cycle ≤ 0.2
- 6. For a device mounted on FR-4 PCB with minimum recommended pad layout.
- 7. For a device mounted on FR-4 PCB with 1inch² copper pad layout.







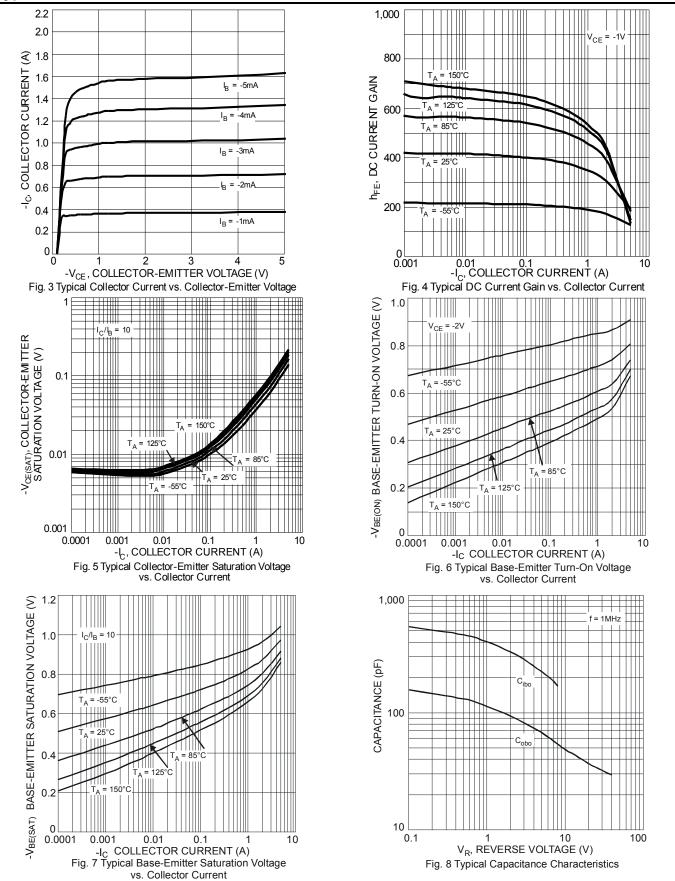
Electrical Characteristics (@TA = 25°C unless otherwise specified)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Conditions
Collector-Base Breakdown Voltage	BV _{CBO}	-40	_	_	V	$I_C = -100 \mu A$
Collector-Emitter Breakdown Voltage (Note 8)	BV _{CEO}	-40	_	_	V	I _C = -10mA
Emitter-Base Breakdown Voltage	BV_{EBO}	-6	_	_	V	I _E = -100μA
Collector-Base Cutoff Current	I _{CBO}		_	-100	nA	$V_{CB} = -30V, I_{E} = 0$
Collector-base Cutoff Current				-50	μΑ	$V_{CB} = -30V$, $I_{E} = 0$, $T_{A} = 150$ °C
Emitter-Base Cutoff Current	I _{EBO}	_	_	-100	nA	$V_{EB} = -5V, I_C = 0$
	h _{FE}	250	_	_		$V_{CE} = -2V, I_{C} = -0.5A$
DC Current Gain (Note 8)		200	350			$V_{CE} = -2V, I_{C} = -1A$
Do Current Gain (Note 6)		150	_	_		$V_{CE} = -2V, I_{C} = -2A$
		50	_	_		$V_{CE} = -2V, I_{C} = -5A$
			_	-120		$I_C = -0.5A$, $I_B = -5mA$
	V _{CE(sat)}			-170		$I_C = -1A$, $I_B = -10mA$
Collector-Emitter Saturation Voltage (Note 8)			-70	-160	mV	I _C = -2A, I _B = -200mA
			-165	-340		$I_C = -4A$, $I_B = -200mA$
			-150	-375		$I_C = -5A$, $I_B = -500mA$
Equivalent On-Resistance	R _{CE(sat)}		-30	-75	mΩ	I _C = -5A, I _B = -500mA
Base-Emitter Saturation Voltage				-1.1	V	$I_C = -4A$, $I_B = -200mA$
base-Emilier Saturation Voltage	V _{BE(sat)}		_	-1.2	V	$I_C = -5A$, $I_B = -500mA$
Base-Emitter Turn-on Voltage	V _{BE(on)}		_	-1.0	V	$V_{CE} = -2V, I_{C} = -2A$
Transition Frequency	f _T	60	_	_	MHz	$V_{CE} = -10V$, $I_{C} = -0.1A$, $f = 100MHz$
Collector Capacitance	Cc		_	105	pF	$V_{CB} = -10V$, $I_{E} = 0A$, $f = 1MHz$
Turn-On Time	t _{on}		63		ns	
Delay Time	t_d		15	_	ns	
Rise Time	t _r	_	48	_	ns	$V_{CC} = -10V, I_C = -2A,$
Turn-Off Time	t _{off}		280	_	ns	I _{B1} = -I _{B2} = -200mA
Storage Time	ts		232	_	ns	
Fall Time	t _f		48		ns	

Notes: 8. Measured under pulsed conditions. Pulse width = 300 μ s. Duty cycle \leq 2%.



Typical Electrical Characteristics (@TA = 25°C unless otherwise specified)

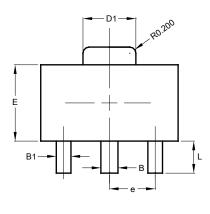


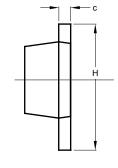


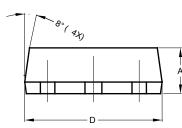
Package Outline Dimensions

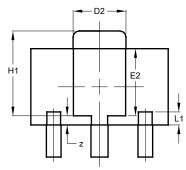
Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT89







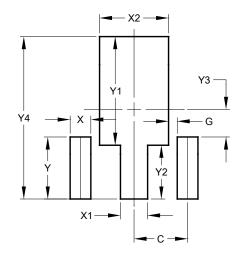


SOT89					
Dim	Min	Max	Тур		
Α	1.40	1.60	1.50		
В	0.50	0.62	0.56		
B1	0.42	0.54	0.48		
С	0.35	0.43	0.38		
D	4.40	4.60	4.50		
D1	1.62	1.83	1.733		
D2	1.61	1.81	1.71		
E	2.40	2.60	2.50		
E2	2.05	2.35	2.20		
е	-	-	1.50		
Н	3.95	4.25	4.10		
H1	2.63	2.93	2.78		
L	0.90	1.20	1.05		
L1	0.327	0.527	0.427		
Z	0.20	0.40	0.30		
All	All Dimensions in mm				

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT89



Dimensions	Value (in mm)		
Dillielisions			
С	1.500		
G	0.244		
X	0.580		
X1	0.760		
X2	1.933		
Υ	1.730		
Y1	3.030		
Y2	1.500		
Y3	0.770		
Y4	4.530		



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